Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
		@pd<"20020602"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/07 15:10
		@pd<"20020602"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/07 15:10
		S49	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/07 15:08
		capacitor and surface near roughness and capacitance near density and S20	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 14:58
		capacitor and barium near strontium near titanium near oxide and S20 and surface near roughness near S21 ra	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 14:42
		"5,967,795" 5,712,503; Ueno, et "al.", U.S. "Pat." "No." "5,789,311"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/08 15:00
L1	1	"5886364".pn. and "43"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/08 15:59
L2	0	"5916642.pn"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/08 15:59

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L3	0	"5916642.pn."	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/08 15:59
L4	2	"5916642".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/08 16:52
L5	2	"6331473".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/08 16:52
S1	5479	filed near (shield plate relief)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 12:42
S2	10331	field near (shield plate relief)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/25 17:52
S3	67783	soi or (silicon near on near insulator)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/25 17:52
S4	546	S2 and S3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/25 17:52
S5	362	S4 and @ad<"20020604"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/25 17:58

S6	304	S4 and metal\$8 and (@ad<"20020604" or @rlad<"20020604")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/25 18:02
S7	298	S4 and metal\$8 and (@ad<"20020604" or @rlad<"20020604") and between	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/25 18:02
S8	39	("4065781" "4091527" "4309715" "4313809" "4507846" "4700454" "4766482" "4778775" "4907053").PN. OR ("4996575").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/04/25 18:04
S9	48	("20010030722" "20020080295" "20020093019" "20030038303" "4609930" "4748485" "4977105" "4984033" "4996575" "5034788" "5103277" "5124769" "5140391" "5185535" "5198379" "5233211" "5246882" "5273921" "5275972" "5281840" "5294821" "5315132" "5327001" "5359219" "5371398" "5470048" "5463483" "5470793" "5475238" "5485019" "5506436" "5521107" "5532850" "5580802" "5604368" "5621224" "5646424" "5702963" "5807772" "5818076" "5917221" "6054734" "6225150" "6252248" "6323068" "6330044" "6479333" "6603453").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/04/25 18:28
S10	14	(S9 S8 S7) and adhesive	US-PGPUB; USPAT; USOCR	OR	ON	2006/04/25 18:29
S11	2	("5198379").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/26 11:47
S12	5506	filed near (shield plate relief)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 12:43

S13	10762	field near (shield plate relief) .	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 12:43
S14	73294	soi or silicon-on-insulator	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 12:43
S15	17576	bipolar same (pnp or npn)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:32
S16	1028	S14 and S15	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON .	2006/09/21 12:44
S17	72	S16 and (field near (plate or electrode or conductor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 12:48
S18	813	S16 and gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 12:45
S19	8246	257/347,350,351,526,E27.112,E29. 009,E29.01,E29.182,E29.184.ccls. 438/152,155.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 12:46
S20	22788584	@ad<"20020604" @rlad<"20020604"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR ,	ON	2006/09/21 12:46

S21	57	S17 and S20	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 12:46
S22	51	S16 and S13	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 12:48
S23	78	S22 andl9	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 12:48
S24	38	S22 and S20	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:00
S25	557	(field near plates) same (double multiple second two) and (bipolar bjt) and S20	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:00
S26	603	(field near plates) same (double multiple second two) and (bipolar bjt pnp npn) and S20	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:09
S27	113	(field near plates) same (double multiple second two) same (bipolar bjt pnp npn) and S20	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:09
S28	626	(field near plates metallization) same (double multiple second two) same (bipolar bjt pnp npn) and S20	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:09

S29	2	"5198379".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:11
S30	0	filed near plate and electrically near shield and (bjt bipolar near transistor) and S20	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:11
S31	0	filed near plates and electrically near shield and (bjt bipolar near transistor) and S20	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:11
S32	0	filed near plates same electrically near shield and (bjt bipolar near transistor) and S20	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:12
S33	0	field near plates same electrically near shield and (bjt bipolar near transistor) and S20	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:13
S34	16	electrically near shield and (bjt bipolar near transistor) and S20	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:18
S35	33732	pnp near transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:18
S36	1	pnp near transistor and filed near plates	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:19

S37	192	pnp near transistor and field near plates	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:19
S38	153	pnp near transistor and field near plates and S20	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:30
539	2	("6252248").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/21 13:32
S40	11531	(bipolar same (pnp or npn)) near transistor bjt	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:33
S41	11	(("6190948") or ("5420457") or ("5440161") or ("5731627") or ("5973341") or ("6118154")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/21 13:34
S42	6	(("6190948") or ("5420457") or ("5440161") or ("5731627") or ("5973341") or ("6118154")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR , .	OFF	2006/09/21 13:36
543	1	filed near plate and bjt	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:36
S44	42	field near plate and bjt	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR '	ON	2006/09/21 13:41

S45	0	capacitor and barium near strontium near titanium near oxide and S20 and surface near roughness near10 ra	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB	OR .	ON	2006/09/21 14:43
S46	15	capacitor and barium near strontium near titanium near oxide and S20 and surface near roughness	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 14:57
S47	104	capacitor and surface near roughness and capacitance near density	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 14:58
S48	22841012	@ad<"20020602" @rlad<"20020602"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/07 14:50
S49	22841012	@ad<"20020602" @rlad<"20020602"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/07 15:09
S50	22837812	@ad<"20020604" @rlad<"20020504"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/07 15:09
S51	22841012	@ad<"20020602" @rlad<"20020602"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/07 15:09
S52	30337582	@pd<"20020602"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/07 15:11

S53	22846531	@ad<"20020604" @rlad<"20020604"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/07 15:11
S54	2	"6335540".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/07 15:16
S55	2	"5886364".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/07 15:16
S56	1	"5886364".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2007/03/07 16:53
S57	36	"5916642"	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2007/03/07 16:53
S58	2	("5916642").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/03/07 17:24
S59	1938	amorphous near graphite	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/07 17:25
S60	93	amorphous near graphite and transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/07 18:09

S61 17 crystalline near shell and wire	US-PGPUB; OR USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ON 2007/03/07 18:10
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